Over voltage and over current protection IC

Description

HM4802 is an Over-Voltage-Protection (OVP) IC. The device will switch off internal MOSFET to disconnect VIN to OUT to protect load when any of input voltage, input current over the threshold. The Over temperature protection (OTP) function monitors chip temperature to protect the device.

Application

- PND
- Tablet
- HD Player
- OTT
- Digital Cameras
- Digital Videos

Features

- High voltage technology
- Maximum input voltage :30V
- Output power ON time :8ms(Typ)
- OVP threshold voltage :5.8V
- OVP response time :<1us
- Output auto discharge
- Small Package :DFN8L（0203-0.75-0.50）

Ordering information

XX YY：Product code

XXXXX.1：Wafer batch

Fig.1 Top view

Table 1

Package	DFN8L（0203-0.75-0.50）
MOQ	3000 pcs

Typical Application

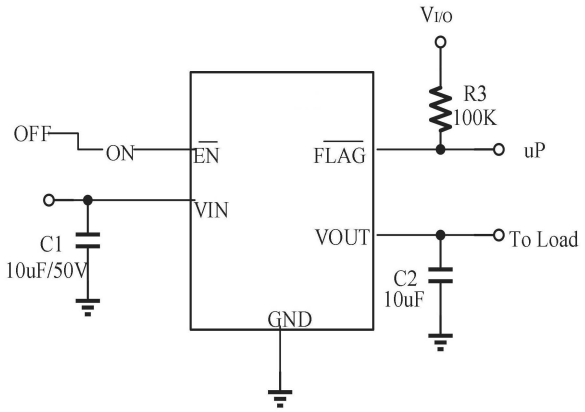
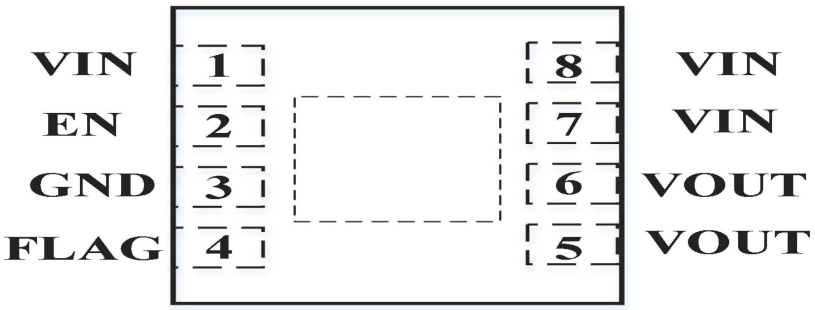


Fig.2

Pin Configuration and Function



HM4802

Fig.3 Pin configuration (Top view)

Table 2

NO.	Symbol	Type	Description
2	EN	INPUT	Enable pin. Active Low.
3	GND	GROUND	Ground
4	FLAG	OUTPUT	Flag Pin. Open-Drain, Active low if any OVP, OTP occur.
5\6	VOUT	OUTPUT	Output pin. Connect to load.
1/7/8	VIN	POWER	Input pin. A 10uF low ESR ceramic capacitor or larger must be connected as close as to this pin. It is recommended to use 50V capacitor or according to application.
Bottom pad		INPUT	Must be connect to VIN on PCB board.

Functional Block Diagram

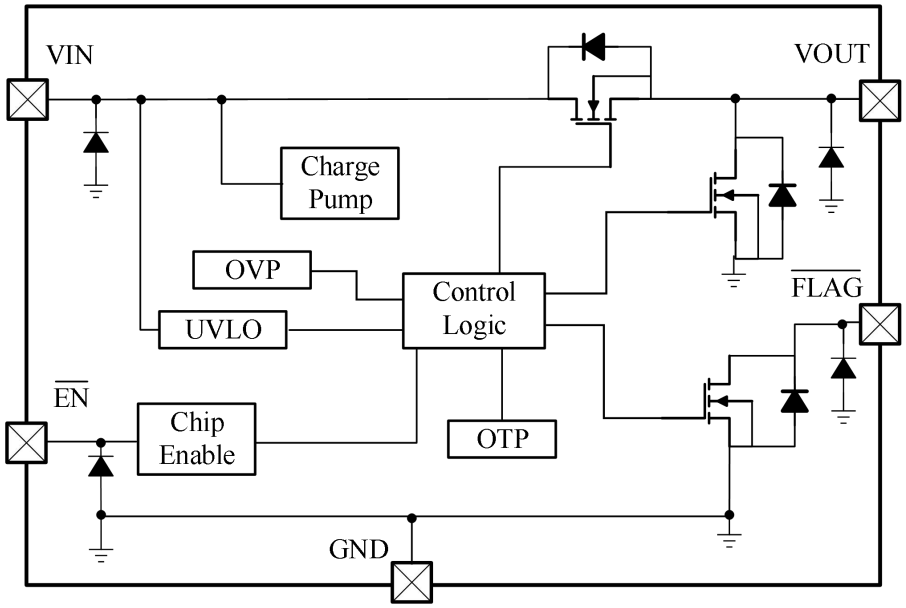


Fig.4

Absolute Maximum Ratings

Table 3

Parameter	Symbol	Value	Unit
Input voltage (IN pin)	V_{IN}	-0.3 ~ 35	V
Output voltage (OUT pin)	V_{OUT}	-0.3 ~ 30	V
Junction temperature	T_J	150	℃
Storage temperature	Tstg	-55 ~ 150	℃
ESD Ratings	HBM	±4000	V
	MM	±200	V

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

Recommend Operating Conditions

Table 4(Ta=25℃, unless otherwise noted)

Parameter	Symbol	Value	Unit
Input voltage	V_{IN}	3.5 ~ 35	V
Output current	I_{OUT}	3	A
Ambient operating temperature	Topr	-40 ~ 85	℃

Electrical Characteristics

Table 5

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
DC characteristics and Power-ON-Reset						
Input quiescent current	IQ	Vin=5v,Iout=0A		170	260	uA
IN-to-OUT ON resistance	RON	Vin=5v,Iout=3A		40		mΩ
Output auto discharge resistance	RDISCHARGE			500		Ω
Under voltage lock out threshold	UVLO	Vin increasing from 0~3V		3.2		V
Under voltage lock out hysteresis	VHYS-UVLO	Vin decreasing from 3~0V		300		mV
Output power-on time	TON	Vin=0 -> 5V to output ON	6	8	10	ms
EN Threshold Voltage	VENL				0.4	V
	VENH		1.2			V
EN to GND current	I_{EN}				2	uA
Input Over-Voltage-Protection (OVP)						
OVP threshold Voltage	$V_{OVP}(th)$			5.8		V
OVP active time	T_{OVP}	VIN= 5 -> 10V			1	us
OVP recovery time	$T_{ON(OVP)}$	VIN=10 -> 5V to output ON	6	8	10	ms
Over-Temperature-Protection (OTP)						
OTP threshold				155		℃
OTP hysteresis				40		℃
Power Switch Body Diode						
Forward peak surge current	I_{FSM}	Pulse Width=10ms			15	A
		Pulse Width=20us			50	A

Package Outline

DFN8L（0203-0.75-0.50）

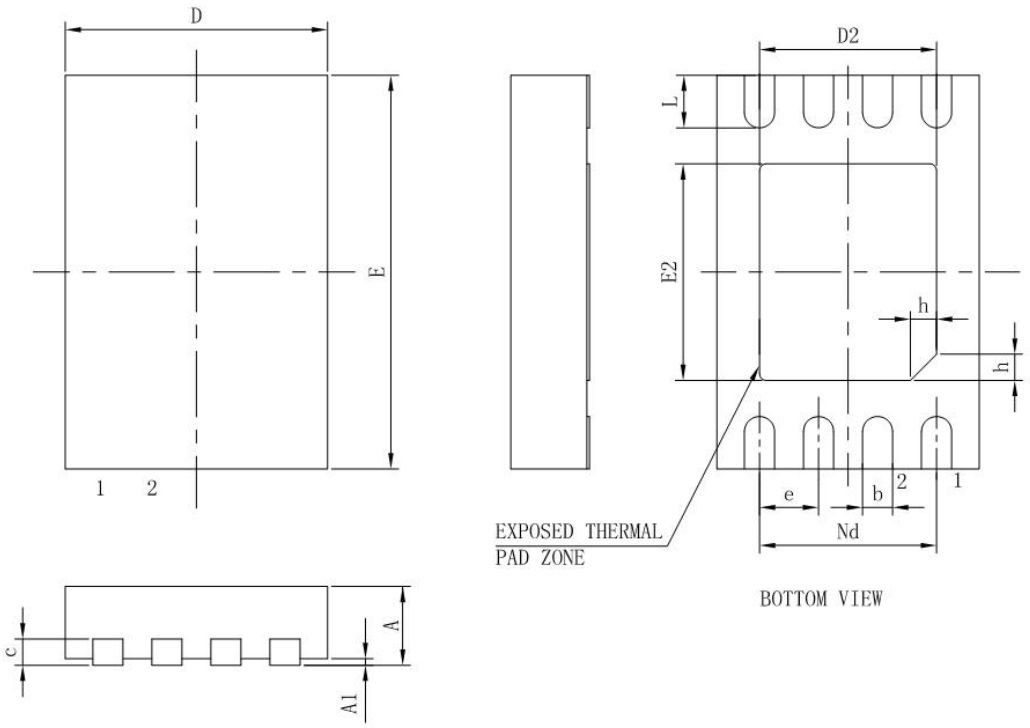


Fig. 5 Package outline

Table 6

Symbol	Min	Type	Max
A	0.70	0.75	0.80
A1	-	0.02	0.05
b	0.20	0.25	0.30
c	0.18	0.20	0.25
D	1.90	2.00	2.10
D2	1.40	1.50	1.60
E	2.90	3.00	3.10
E2	1.50	1.60	1.70
e	0.50BSC		
Nd	1.50BSC		
L	0.30	0.40	0.50
h	0.20	0.25	0.30